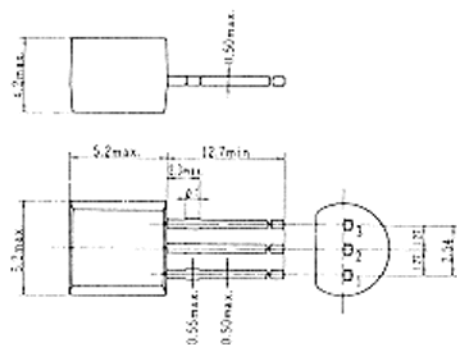


2SC1856

SILICON NPN

VHF AMPLIFIER

VHF TV TUNER RF AMPLIFIER



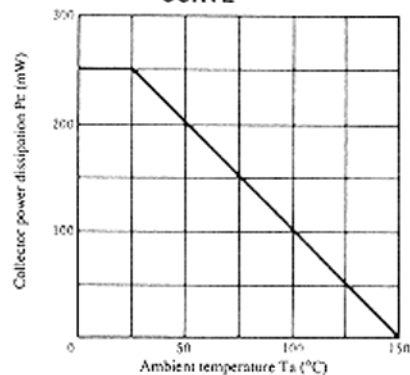
(JEDEC TO-92)

1. Base
 2. Emitter
 3. Collector
- (Dimensions in mm)

■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

Item	Symbol	2SC1856	Unit
Collector to base voltage	V _{CB0}	20	V
Collector to emitter voltage	V _{CE0}	20	V
Emitter to base voltage	V _{EB0}	3	V
Collector current	I _C	20	mA
Emitter current	I _E	-20	mA
Collector power dissipation	P _C	250	mW
Junction temperature	T _J	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

MAXIMUM COLLECTOR DISSIPATION CURVE

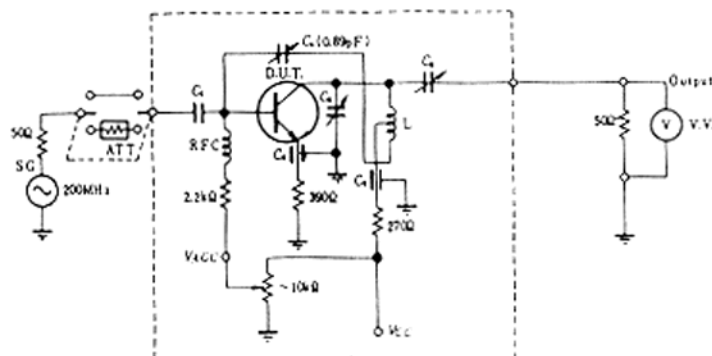


■ ELECTRICAL CHARACTERISTICS (Ta=25°C)

Item	Symbol	Test Condition	min.	typ.	max.	Unit
Collector to base breakdown voltage	V _{(BR)CBO}	I _C = 100μA, I _E = 0	20	—	—	V
Collector to emitter breakdown voltage	V _{(BR)CEO}	I _C = 3mA, R _{BE} = ∞	20	—	—	V
Emitter to base breakdown voltage	V _{(BR)EBO}	I _E = 100μA, I _C = 0	3	—	—	V
Collector cutoff current	I _{CBO}	V _{CE} = 20V, I _E = 0	—	—	100	nA
DC current transfer ratio	h _{FE}	V _{CE} = 10V, I _C = 2mA	20	—	200	
Gain bandwidth product	f _T	V _{CE} = 10V, I _C = 2mA	400	550	—	MHz
Reverse transfer capacitance	C _{re*}	V _{CB} = 12V, I _E = 0 f = 1MHz, Emitter Common	—	0.35	0.45	pF
Power gain	PG	V _{CC} = 12V, V _{AGC} = 1.7V, f = 200MHz, (I _C ≈ 2mA)	18	22	27	dB
Noise figure	NF	V _{CE} = 10V, I _C = 2mA, f = 200MHz	—	2.5	3.2	dB
AGC voltage	V _{AGC}	V _{CC} = 12V, GR = 30dB, f = 200MHz	4.3	4.7	5.1	V

* Measured by the balanced type capacitance bridge. (Emitter lead is connected to earth terminal of the tester.)

PG, NF and V_{AGC} Test Circuit

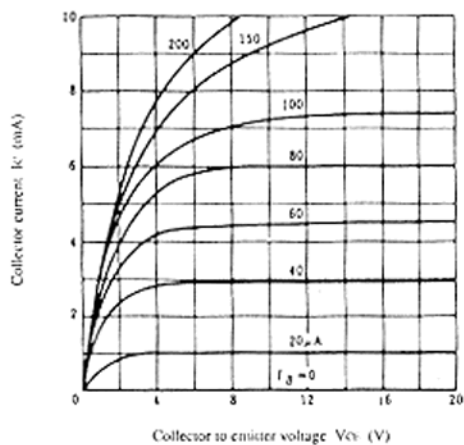


C_1 : 0.005 μ F
 C_2 :
 C_3 : } 0.005 μ F
 C_4 : 10pF max
 C_5 : 10pF max
 C_6 : 10pF max
 L : 1.0mm Cu wire plated with Sn 4 T, 9.5mm inside dia, ground with 2 T from collector, pitch 2.0mm.
 ATT: 30dB

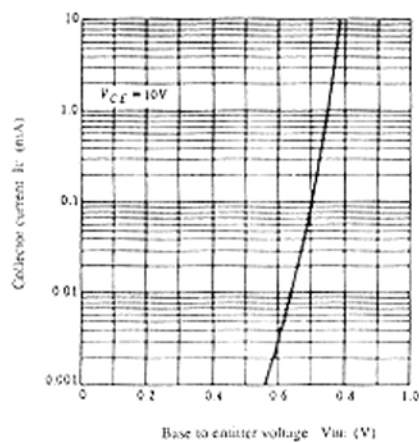
V_{AGC} Test Procedure

1. Set up at $V_{CC} = 12V$ and $V_{ACC} = 1.7V$.
2. Adjust C_3 for max. output with ATT (30 dB) connected.
3. Adjust output of SG for $V_{out} = 1mV$.
4. Then, remove ATT and adjust V_{ACC} for $V_{out} = 1mV$.
(at this time, output of SG and C_3 should not be changed.)
5. The V_{ACC} value adjusted is defined as the AGC voltage at 30 dB attenuation.

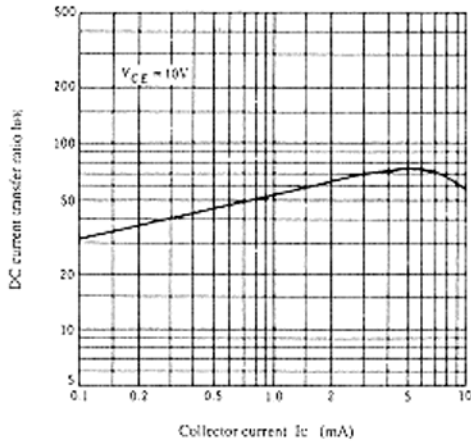
TYPICAL OUTPUT CHARACTERISTICS



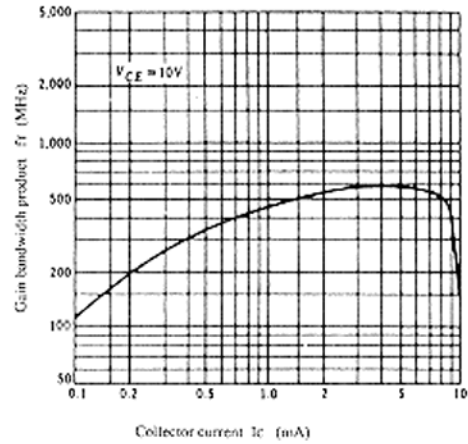
TYPICAL TRANSFER CHARACTERISTICS



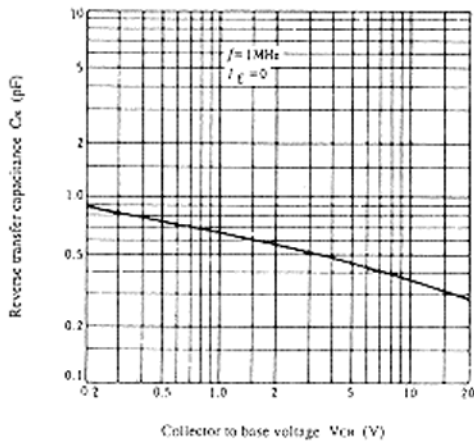
DC CURRENT TRANSFER RATIO VS. COLLECTOR CURRENT



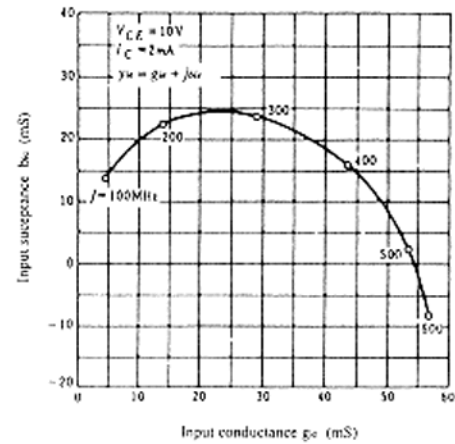
GAIN BANDWIDTH PRODUCT VS. COLLECTOR CURRENT



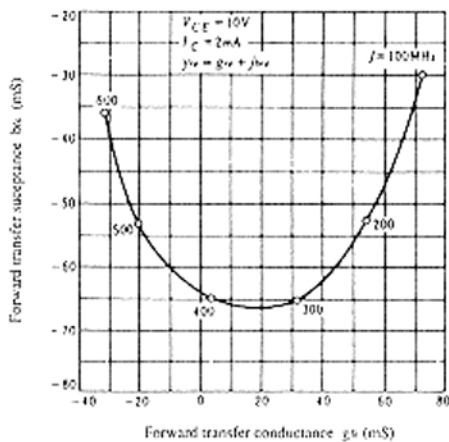
REVERSE TRANSFER CAPACITANCE VS. COLLECTOR TO BASE VOLTAGE



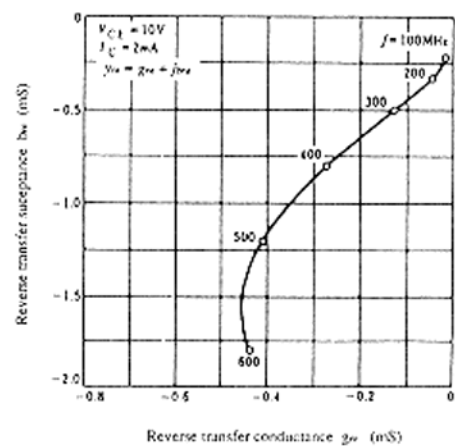
INPUT ADMITTANCE VS. FREQUENCY



FORWARD TRANSFER ADMITTANCE VS. FREQUENCY

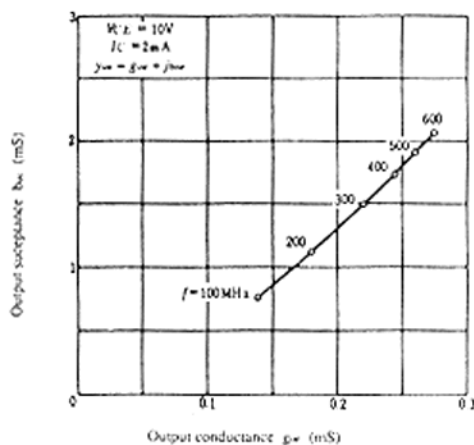


REVERSE TRANSFER ADMITTANCE VS. FREQUENCY

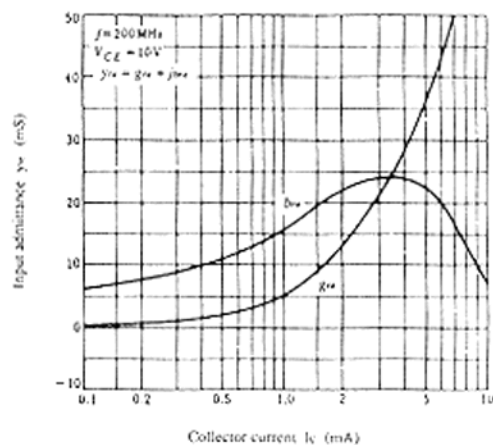


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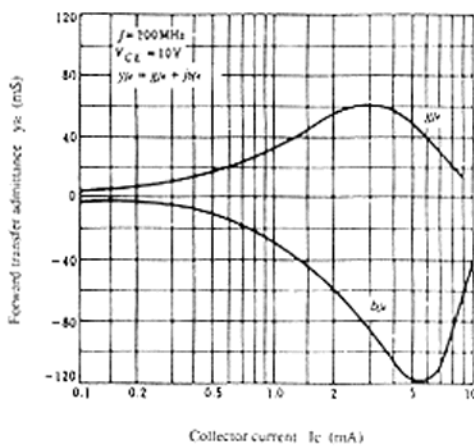
OUTPUT ADMITTANCE VS. FREQUENCY



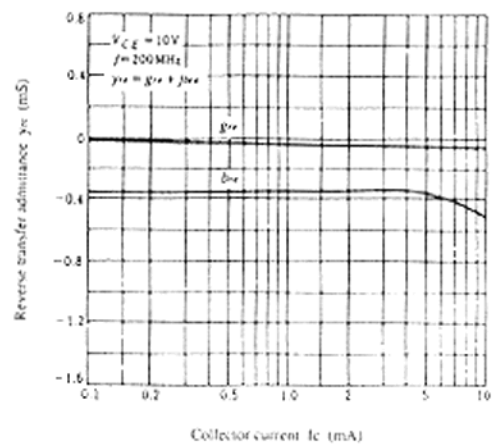
INPUT ADMITTANCE VS. COLLECTOR CURRENT



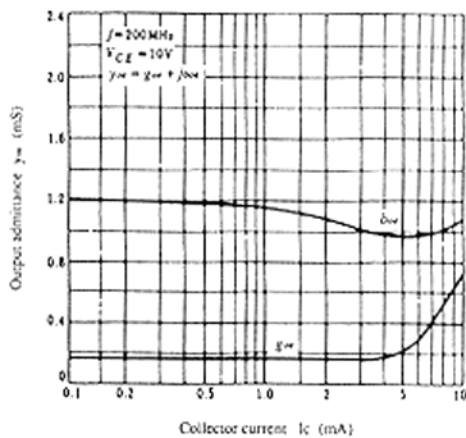
FORWARD TRANSFER ADMITTANCE VS. COLLECTOR CURRENT



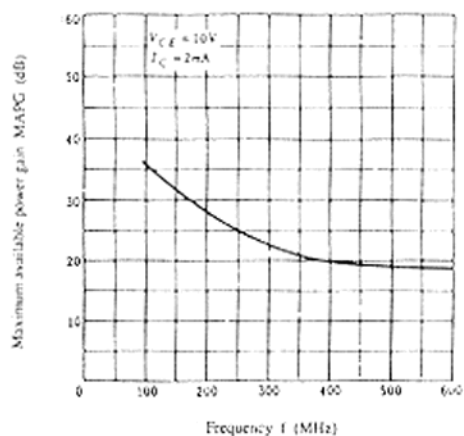
REVERSE TRANSFER ADMITTANCE VS. COLLECTOR CURRENT



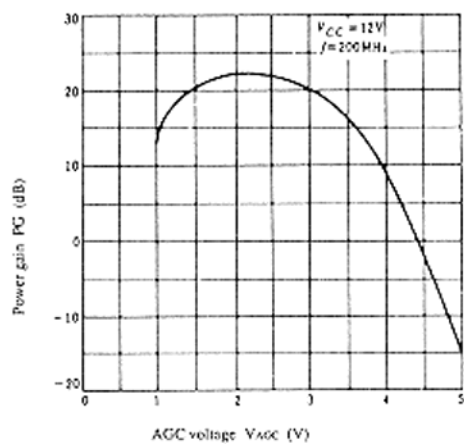
OUTPUT ADMITTANCE VS. COLLECTOR CURRENT



MAXIMUM AVAILABLE POWER GAIN VS. FREQUENCY



POWER GAIN VS. AGC VOLTAGE



POWER GAIN & NOISE FIGURE VS. COLLECTOR CURRENT

